

MAPC-A1102

Rev. V5

Features

- MACOM PURE CARBIDE_® Amplifier Series
- Suitable for Linear & Saturated Applications
- CW & Pulsed Operation: 150 W Output Power
- Internally Pre-Matched
- 50 V Operation
- Compatible with MACOM Power Management Bias Controller/Sequencer MABC-11040

Applications

Military Radio Communications, RADAR, Avionics, Digital Cellular Infrastructure, RF Energy, and Test Instrumentation.

Description

The MAPC-A1102 is a high power GaN on Silicon Carbide HEMT D-mode amplifier suitable for DC - 3.5 GHz frequency operation. The device supports both CW and pulsed operation with output power levels of at least 150 W (51.75 dBm) in an air cavity ceramic package.

Typical Performance:

- Measured under load-pull at 2.5 dB compression, 100 µs pulse width, 10% duty cycle
- V_{DS} = 50 V, I_{DQ} = 260 mA, T_C = 25°C

Frequency (GHz)	Output Power ¹ (dBm)	Gain ² (dB)	η _□ ² (%)
0.9	52.7	24.7	70.4
1.4	52.9	21.4	73.5
2.0	52.8	15.7	70.3
2.5	53.4	17.0	63.2
3.0	53.0	16.5	66.8
3.5	52.7	15.7	70.1

• $V_{DS} = 28 \text{ V}, I_{DQ} = 130 \text{ mA}, T_{C} = 25^{\circ}\text{C}$

Frequency (GHz)	Output Power ¹ (dBm)	Gain² (dB)	η _D ² (%)
0.9	50.0	22.8	70.4
1.4	50.0	19.6	72.1
2.0	50.3	14.0	68.9
2.5	50.5	15.0	66.5
3.0	50.4	14.4	70.1
3.5	49.9	13.6	73.3

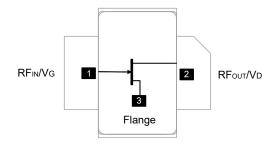
- 1. Load impedance tuned for maximum output power.
- 2. Load impedance tuned for maximum drain efficiency.



AC-360S-2

AC-360B-2

Functional Schematic



Pin Configuration

Pin#	Pin Name	Function
1	RF _{IN} / V _G	RF Input / Gate
2	RF _{OUT} / V _D	RF Output / Drain
3	Flange ³	Ground / Source

The flange on the package bottom must be connected to RF, DC and thermal ground.

Ordering Information

Part Number	Package
MAPC-A1102-AS000	Bulk Quantity
MAPC-A1102-ASTR1	Tape and Reel
MAPC-A1102-ASSB1	Sample Board
MAPC-A1102-AB000	Bulk Quantity
MAPC-A1102-ABTR1	Tape and Reel

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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RF Electrical Characteristics: $T_C = 25^{\circ}C$, $V_{DS} = 50 \text{ V}$, $I_{DQ} = 260 \text{ mA}$ Note: Performance in MACOM Evaluation Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed ⁴ , 3.5 GHz	Gss	-	16.3	-	dB
Power Gain	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	G _{SAT}	-	13.8	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	η _{SAT}	-	65.5	-	%
Saturated Output Power	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	P _{SAT}	-	52.0	-	dBm
Gain Variation (-40°C to +85°C)	Pulsed ⁴ , 3.5 GHz	ΔG	-	0.016	-	dB/°C
Power Variation (-40°C to +85°C)	Pulsed ⁴ , 3.5 GHz	ΔP2.5dB	-	0.0048	-	dB/°C
Power Gain	Pulsed ⁴ , 3.5 GHz, P _{OUT} = 51.75 dBm	G _P	-	14.0	-	dB
Drain Efficiency	Pulsed ⁴ , 3.5 GHz, P _{OUT} = 51.75 dBm	η	-	65.0	-	%
Ruggedness: Output Mismatch	All phase angles	Ψ	VSWR = 10:1, No Damage		age	

RF Electrical Specifications: $T_A = 25^{\circ}C$, $V_{DS} = 50 \text{ V}$, $I_{DQ} = 260 \text{ mA}$ Note: Performance in MACOM Production Test Fixture, 50Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Power Gain	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	G _{SAT}	13.0	14.0	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	η _{SAT}	53.5	58.4	-	%
Saturated Output Power	Pulsed ⁴ , 3.5 GHz, 2.5 dB Gain Compression	P _{SAT}	50.4	51.8	-	dBm
Power Gain	Pulsed ⁴ , 3.5 GHz, P _{IN} = 38 dBm	G _P	13.0	13.9	-	dB
Drain Efficiency	Pulsed ⁴ , 3.5 GHz, P _{IN} = 38 dBm	η	53.5	58.6	-	%

^{4.} Pulse details: 100 μs pulse width, 10% Duty Cycle.

DC Electrical Characteristics T_A = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	$V_{GS} = -8 \text{ V}, V_{DS} = 130 \text{ V}$	I _{DLK}	-	-	17.8	mA
Gate-Source Leakage Current	V _{GS} = -8 V, V _{DS} = 0 V	I _{GLK}	-	-	17.8	mA
Gate Threshold Voltage	$V_{DS} = 50 \text{ V}, I_{D} = 17.76 \text{ mA}$	V _T	-3.6	-2.8	-	V
Gate Quiescent Voltage	V _{DS} = 50 V, I _D = 260 mA	V_{GSQ}	-3.2	-2.6	-2.2	V
On Resistance	$V_{GS} = 2 \text{ V}, I_D = 133.2 \text{ mA}$	R _{ON}	-	0.2	-	Ω
Maximum Drain Current	V _{DS} = 7 V pulsed, pulse width 300 μs	I _{D, MAX}	-	10.3	-	Α



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Absolute Maximum Ratings^{5,6,7,8,9}

Parameter	Absolute Maximum
Drain Source Voltage, V _{DS}	130 V
Gate Source Voltage, V _{GS}	-10 to 3 V
Gate Current, I _G	17.76 mA
Storage Temperature Range	-65°C to +150°C
Case Operating Temperature Range	-40°C to +85°C
Channel Operating Temperature Range, T _{CH}	-40°C to +225°C
Absolute Maximum Channel Temperature	+250°C

Exceeding any one or combination of these limits may cause permanent damage to this device.

Thermal Characteristics¹⁰

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis	$V_{DS} = 50 \text{ V},$ $T_{C} = 85^{\circ}\text{C}, T_{CH} = 225^{\circ}\text{C}$	$R_{\theta}(FEA)$	1.64	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C	$R_{\theta}(IR)$	1.28	°C/W

^{10.} Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

MACOM does not recommend sustained operation above maximum operating conditions.

Operating at drain source voltage $V_{DS} < 55 \text{ V}$ will ensure MTTF > 2 x 10⁶ hours.

Operating at nominal conditions with $T_{CH} \le 225^{\circ}\text{C}$ will ensure MTTF > 2 x 10⁶ hours.

MTTF may be estimated by the expression MTTF (hours) = A $e^{\frac{[B+C/(T+273)]}{2}}$ where T is the channel temperature in degrees Celsius, A = 1, B = -38.215, and C = 26,343.



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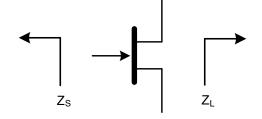
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50 V Pulsed⁴ Load-Pull Performance: Reference Plane at Device Leads

		Maximum Output Power $V_{DS} = 50 \text{ V, } I_{DQ} = 260 \text{ mA, } T_{C} = 25^{\circ}\text{C, } P2.5 \text{dB}$						
			V _{DS} = 50	V, I _{DQ} = 260 m	$A, I_C = 25^{\circ}C,$	P2.5dB		
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _D (%)	AM/PM (°)	
0.9	0.47 +j0.56	5.01 + j1.39	22.7	52.7	185.4	62.7	-0.1	
1.4	0.56 - j1.52	3.67 + j1.08	18.9	52.9	195.0	61.3	0.7	
2.0	1.13 - j3.31	2.90 + j0.27	14.5	52.8	191.4	62.2	-1.7	
2.5	1.02 - j5.44	2.76 - j0.86	15.2	53.4	217.8	54.9	0.4	
2.7	1.30 - j6.49	2.55 - j1.01	15.1	53.0	200.9	56.3	0.1	
3.0	2.16 - j8.50	2.23 - j1.37	14.7	53.0	199.5	57.1	0.3	
3.5	9.58 - j11.3	1.88 - j2.04	14.0	52.7	184.5	58.3	-3.3	

		Maximum Drain Efficiency							
			V _{DS} = 50 V, I _{DQ} = 260 mA, T _C = 25°C, P2.5dB						
Frequency (GHz)	Z _{SOURCE} (Ω)	Z_{LOAD}^{12} (Ω)	Gain (dB)	Р _{оит} (dBm)	P _{out} (W)	η _D (%)	AM/PM (°)		
0.9	0.38 + j0.36	6.12 + j5.04	24.7	51.5	142.2	70.4	-4.8		
1.4	0.41 - j1.62	3.63 + j4.77	21.4	50.8	121.1	73.5	0.5		
2.0	1.06 - j3.33	2.32 + j1.94	15.7	51.7	148.9	70.3	-2.1		
2.5	0.85 - j5.37	2.11 + j0.81	17.0	52.2	167.1	63.2	0.6		
2.7	1.06 - j6.38	1.81 + j0.54	17.1	51.8	152.1	68.4	-9.7		
3.0	1.86 - j8.42	1.53 - j0.04	16.7	51.6	143.5	66.8	-1.3		
3.5	7.99 - j11.67	1.08 - j1.08	15.7	51.1	128.2	70.1	-9.1		

Impedance Reference



Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

 Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.

- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.

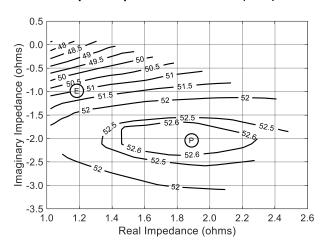


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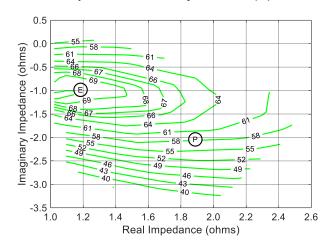
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50 V Pulsed⁴ Load-Pull Performance @ 3.5 GHz

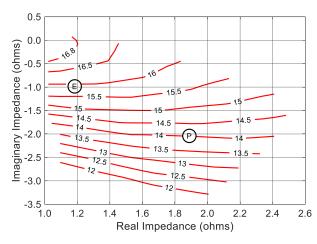
P2.5dB Loadpull Output Power Contours (dBm)



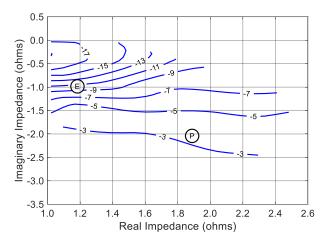
P2.5dB Loadpull Drain Efficiency Contours (%)



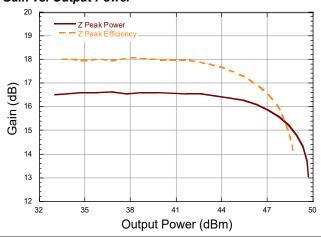
P2.5dB Loadpull Gain Contours (dB)



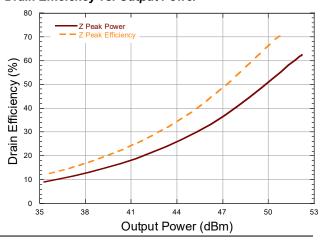
P2.5dB Loadpull AM/PM Contours (°)



Gain vs. Output Power



Drain Efficiency vs. Output Power



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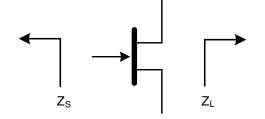
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28 V Pulsed⁴ Load-Pull Performance: Reference Plane at Device Leads

		Maximum Output Power							
			V _{DS} = 28 V, I _{DQ} = 260 mA, T _C = 25°C, P2.5dB						
Frequency (GHz)	Z _{source} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _D (%)	AM/PM (°)		
0.9	0.42 + j0.53	2.96 + j0.37	21.1	50.0	100.0	61.3	-1.7		
1.4	0.61 - j1.64	2.53 - j0.28	16.8	50.0	100.0	59.3	8.0		
2.0	1.20 - j3.40	2.07 - j1.08	12.5	50.3	107.2	60.0	-5.4		
2.5	1.08 - j5.67	2.27 - j1.85	13.4	50.5	112.2	59.2	-0.1		
2.7	1.52 - j6.84	2.04 - j2.12	12.9	50.3	107.2	58.5	-1.3		
3.0	2.57 - j9.05	1.88 - j2.44	12.8	50.4	109.6	61.8	-1.7		
3.5	11.6 - j10.5	1.54 - j3.00	12.1	49.9	97.7	64.1	-5.8		

		Maximum Drain Efficiency							
		V _{DS} = 28 V, I _{DQ} = 260 mA, T _C = 25°C, P2.5dB							
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _D (%)	AM/PM (°)		
0.9	0.35 + j0.1	5.36 + j3.13	22.8	47.9	61.7	70.4	-3.7		
1.4	0.40 - j1.95	3.40 + j3.02	19.6	47.1	51.3	72.1	-1.8		
2.0	1.04 - j3.45	1.93 + j0.46	14.0	48.8	75.8	68.9	-9.1		
2.5	0.93 - j5.74	1.80 - j0.42	15.0	49.2	83.2	66.5	-4.2		
2.7	1.17 - j6.99	1.54 - j0.44	14.9	48.4	69.2	68.6	-6.7		
3.0	2.28 - j9.35	1.30 - j1.06	14.4	48.5	70.8	70.1	-6.2		
3.5	13.8 - j12.0	1.06 - j1.75	13.6	47.5	56.2	73.3	-18.7		

Impedance Reference



 Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

- 11. Load Impedance for optimum output power.12. Load Impedance for optimum efficiency.

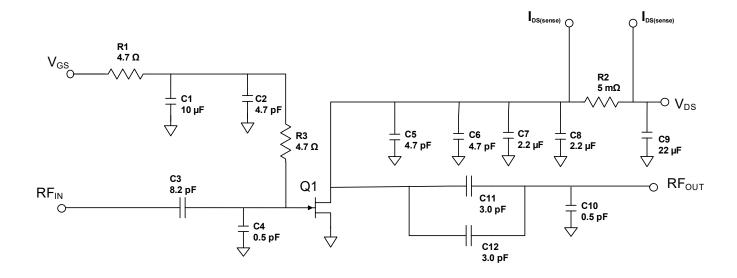
 Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.



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Evaluation Test Fixture and Recommended Tuning Solution: 3.45 - 3.55 GHz



Description

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

Bias Sequencing Turning the device ON

- 1. Set V_{GS} to pinch-off (V_P).
- 2. Turn on V_{DS} to nominal voltage (50 V).
- 3. Increase V_{GS} until I_{DS} current is reached.
- 4. Apply RF power to desired level.

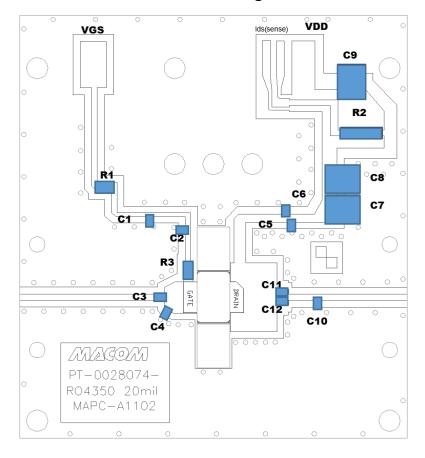
Turning the device OFF

- 1. Turn the RF power OFF.
- 2. Decrease V_{GS} down to V_P pinch-off.
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS}.



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Evaluation Test Fixture and Recommended Tuning Solution: 3.45 - 3.55 GHz



Reference Designator	Value	Tolerance	Manufacturer	Part Number		
C1	10 μF	+/- 10 %	Murata	GRM21BZ71C106KE15L		
C2, C5, C6	4.7 pF	+/- 0.1 pF	Murata	GQM2195C2E4R7BB12D		
C3	8.2 pF	+/- 0.1 pF	Murata	GQM2195C2E8R2BB12D		
C7, C8	2.2 µF	+/- 20%	Murata	KRM55TR72E225MH01L		
C9	22 µF	+/- 20%	Murata	KRM55WR72A226MH01K		
C4, C10	0.5 pF	+/- 0.1 pF	Murata	GQM2195C2ER50BB12D		
C11, C12	3.0 pF	+/- 0.1 pF	Murata	GQM2195C2E3R0BB12D		
R2	5 mΩ	+/- 1%	Susumu	RL7520WT-R005-F		
R1, R3	4.7 Ω	+/- 1%	Panasonic	ERJ-8RQF4R7V		
Q1	Q1 MACOM			MAPC-A1102		
PCB	RO4350, 20 mil, 1 oz. Cu, Au Finish					

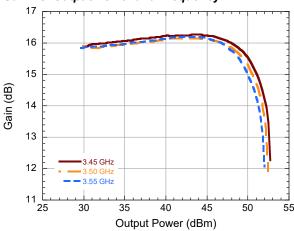


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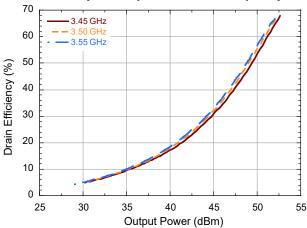
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Typical Performance Curves as Measured in the 3.45 - 3.55 GHz Evaluation Test Fixture: Pulsed⁴ 3.5 GHz, V_{DS} = 50 V, I_{DQ} = 260 mA, T_{C} = 25°C (Unless Otherwise Noted)

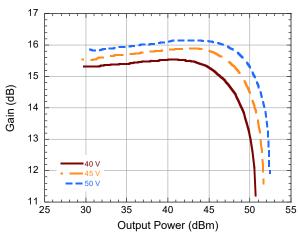
Gain vs. Output Power and Frequency



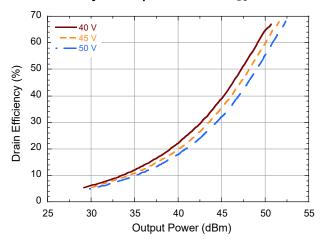
Drain Efficiency vs. Output Power and Frequency



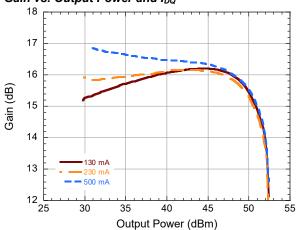
Gain vs. Output Power and V_{DS}



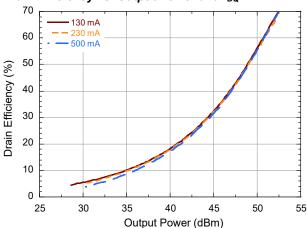
Drain Efficiency vs. Output Power and V_{DS}



Gain vs. Output Power and IDQ



Drain Efficiency vs. Output Power and IDQ



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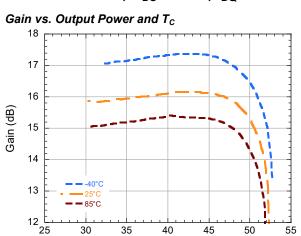
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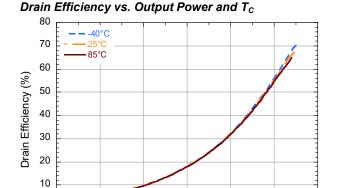
Typical Performance Curves as Measured in the 3.45 - 3.55 GHz Evaluation Test Fixture: Pulsed⁴ 3.5 GHz, V_{DS} = 50 V, I_{DQ} = 260 mA, T_{C} = 25°C (Unless Otherwise Noted)

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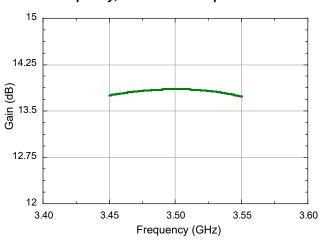
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Gain vs. Frequency, 2.5dB Gain Compression



Output Power (dBm)

Drain Efficiency vs. Frequency, 2.5dB Gain Compression

35

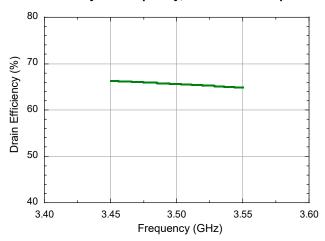
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Output Power (dBm)

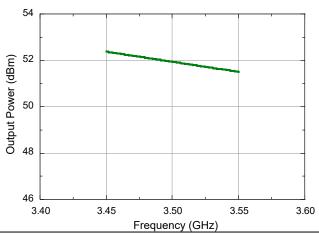
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50

55



Output Power vs. Frequency, 2.5dB Gain Compression



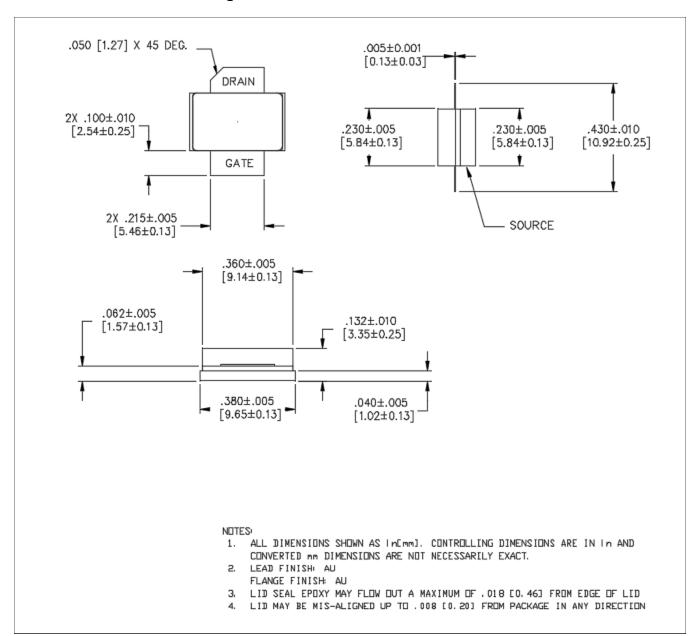
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Lead-Free AC-360S-2 Package Dimensions[†]



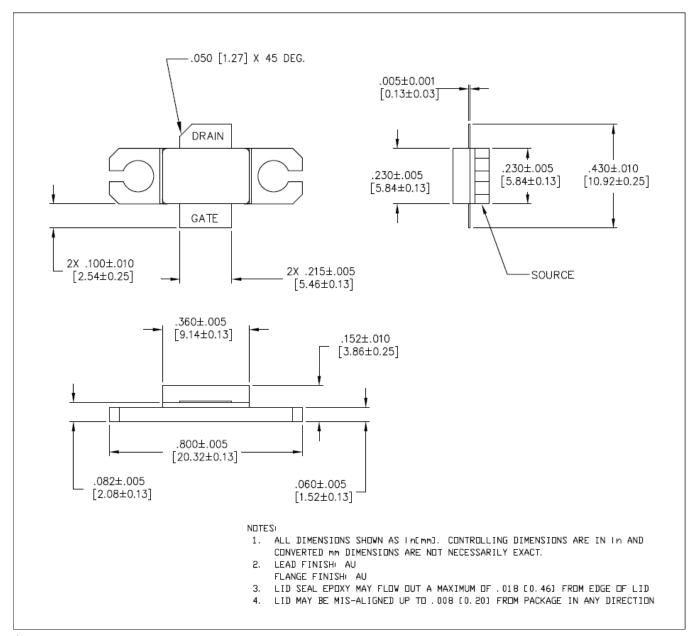
[†] Reference Application Note AN0004363 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.



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Lead-Free AC-360B-2 Package Dimensions[†]



Reference Application Note AN0004363 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.

GaN Amplifier 50 V, 150 W DC - 3.5 GHz



MACOM PURE CARBIDE

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